

140V PNP MEDIUM POWER TRANSISTOR PowerDI[®]5

Features

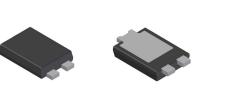
- 43% Smaller than SOT223: 60% Smaller than TO252
- Maximum Height: 1.1mm
- Rated up to 3.2W
- $V_{CEO} = -140V$
- $I_C = -4A$; $I_{CM} = -10A$
- Low Saturation Voltage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q101, PPAP capable, and manufactured in IATF16949 certified facilities), please contact us or your local Diodes representative.
- https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Case: PowerDI®5
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.093 grams (Approximate)

Applications

SLIC DC-DC Converter

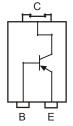


Top View

Bottom View



Device Schematic



Pin-out diagram

Ordering Information (Note 4)

Part Number	Marking	Reel Size (Inches)	Tape Width (mm)	Quantity per Reel
DXT2014P5-13	DXT2014	13	16	5000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



DXT2014 = Product Type Marking Code Dil = Manufacturers' Code Marking K = Factory Designator YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 19 for 2019) WW = Week code (01 to 53)



Maximum Ratings (@T_A = 25°C unless otherwise specified)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-180	V
Collector-Emitter Voltage	V _{CEO}	-140	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	Ic	-4	A
Peak Pulse Current	Ісм	-10	A

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation @ T _A = 25°C (Note 5)	P_{D}	3.2	W
Thermal Resistance, Junction to Ambient Air (Note 5) @T _A = 25°C	$R_{ hetaJA}$	39	°C/W
Power Dissipation @ T _A = 25°C (Note 6)	P _D	1.7	W
Thermal Resistance, Junction to Ambient Air (Note 6) @T _A = 25°C	$R_{ heta JA}$	75	°C/W
Power Dissipation @ T _A = 25°C (Note 7)	P_{D}	0.74	W
Thermal Resistance, Junction to Ambient Air (Note 7) @T _A = 25°C	$R_{ hetaJA}$	169	°C/W
Thermal Resistance, Junction to Collector Terminal	$R_{ heta JT}$	5.6	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

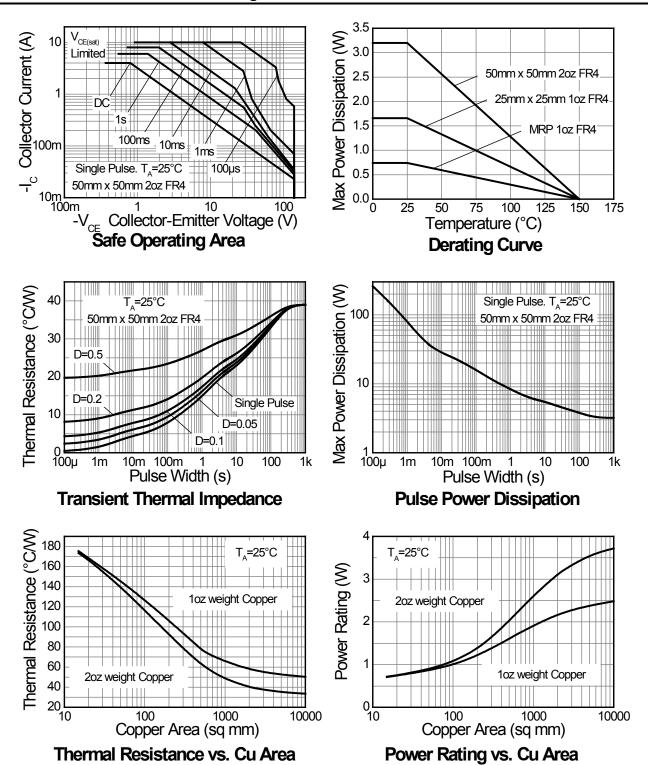
Notes:

- 5. Device mounted on FR-4 PCB, single sided 2 oz. copper, collector pad dimensions 50mm x 50mm.
 6. Device mounted on FR-4 PCB, single sided 1 oz. copper, collector pad dimensions 25mm x 25mm.
 7. Device mounted on FR-4 PCB, single sided 1 oz. copper, minimum recommended pad layout.

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Thermal Characteristics and Derating Information





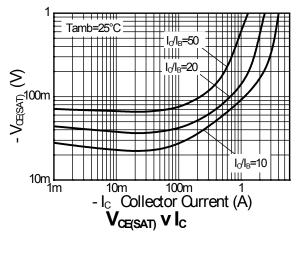
Electrical Characteristics @TA = 25°C unless otherwise specified

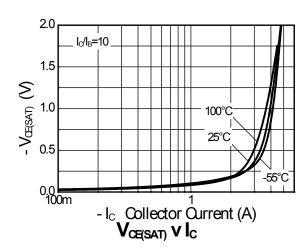
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	V _{(BR)CBO}	-180	-200	_	V	$I_C = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 8)	V _{(BR)CEO}	-140	-160	_	V	I _C = -10mA
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	-7.0	-8.0	_	V	I _E = -100μA
Collector Cutoff Current	I _{CBO}	_	<1	-20	nA	V _{CB} = -150V
Collector Cuton Current				-0.5	μΑ	V _{CB} = -150V, T _{amb} = 100°C
Collector Cutoff Current	I _{CER} R≤1kΩ	_	<1	-20	nA	V _{CB} = -150V
Collector Cuton Current				-0.5	μΑ	V _{CB} = -150V, T _{amb} = 100°C
Emitter Cutoff Current	I _{EBO}	_	<1	-10	nA	V _{EB} = -6V
			-40	-60		$I_C = -0.1A$, $I_B = -5mA$
Collector-Emitter Saturation Voltage (Note 8)	V _{CE(sat)}		-55	-80	mV	$I_C = -0.5A$, $I_B = -50mA$
Collector-Efficier Saturation Voltage (Note o)			-85	-120	IIIV	$I_C = -1A$, $I_B = -100mA$
			-275	-360		$I_C = -3A$, $I_B = -300mA$
Base-Emitter Saturation Voltage (Note 8)	V _{BE(sat)}	_	-940	-1040	mV	$I_C = -3A$, $I_B = -300mA$
Base-Emitter Turn-On Voltage (Note 8)	V _{BE(on)}	_	-830	-930	mV	$V_{CE} = -5V, I_{C} = -3A$
	h _{FE}	100	225	_		$V_{CE} = -5V, I_{C} = -10mA$
DC Current Gain (Note 8)		100 45 —	200	300	_	$V_{CE} = -5V, I_{C} = -1A$
Do Garrent Gain (Note 6)			100	_		$V_{CE} = -5V, I_{C} = -3A$
			5	_		$V_{CE} = -5V, I_{C} = -10A$
Transition Frequency	f⊤	_	120		MHz	$V_{CE} = -10V, I_{C} = -100mA,$
	11					f = 50MHz
Output Capacitance	C _{obo}	_	33	_	pF	V _{CB} = -10V, f = 1MHz
Switching Times	ton	_	42	_	ns	$V_{CC} = -50V, I_C = 1A,$
Cantoning Times	t _{off}		636	_	ns	$I_{B1} = -I_{B2} = -100 \text{mA}$

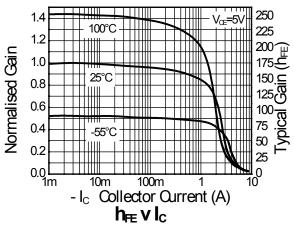
Notes: 8. Pulse Test: Pulse width $\leq 300 \mu s$. Duty cycle $\leq 2.0\%$.

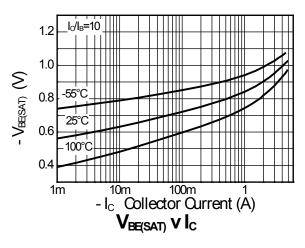


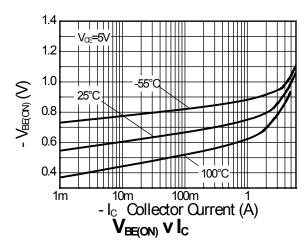
Typical Characteristic







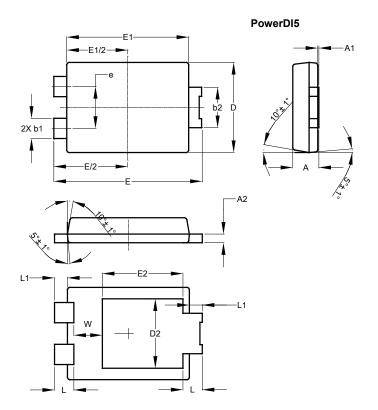






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

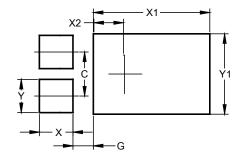


PowerDI5					
Dim	Min	Max	Тур		
Α	1.05	1.15	1.10		
A1	0.00	0.05			
A2	0.33	0.43	0.381		
b1	0.80	0.99	0.89		
b2	1.70	1.88	1.78		
D	3.90	4.05	3.966		
D2			3.054		
Е	6.40	6.60	6.51		
е			1.84		
E1	5.30	5.45	5.37		
E2	-	-	3.549		
L	0.75	0.95	0.85		
L1	0.50	0.65	0.57		
W	1.10	1.41	1.255		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5



Dimensions	Value (in mm)
С	1.840
G	0.852
Х	1.400
X1	4.860
X2	1.310
Y	1.390
V1	2 260



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